

1N5400G - 1N5408G

GLASS PASSIVATED JUNCTION SILICON RECTIFIERS

PRV : 50 - 1000 Volts

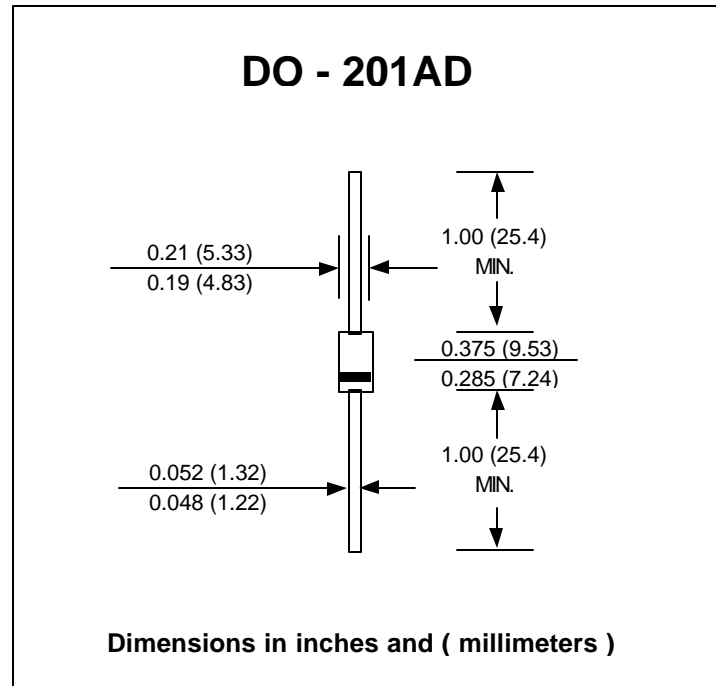
Io : 3.0 Amperes

FEATURES :

- * Glass passivated chip
- * High current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop

MECHANICAL DATA :

- * Case : DO-201AD Molded plastic
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Color band denotes cathode end
- * Mounting position : Any
- * Weight : 1.21 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

RATING	SYMBOL	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G	UNIT
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 75 °C	I _{F(AV)}	3.0							Amps.
Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I _{FSM}	150							Amps.
Maximum Forward Voltage at I _F = 3.0 Amperes.	V _F	1.0							Volts
Maximum DC Reverse Current Ta = 25 °C at rated DC Blocking Voltage Ta = 100 °C	I _R	5.0							μA
	I _{R(H)}	50							μA
Typical Junction Capacitance (Note1)	C _J	50							pF
Typical Thermal Resistance (Note2)	R _{θJA}	15							°C/W
Junction Temperature Range	T _J	- 65 to + 175							°C
Storage Temperature Range	T _{STG}	- 65 to + 175							°C

Notes :

- (1) Measured at 1.0 MHz and applied reverse voltage of 4.0V_{DC}
- (2) Thermal resistance from Junction to Ambient at 0.375" (9.5mm) Lead Lengths, P.C. Board Mounted.

RATING AND CHARACTERISTIC CURVES (1N5400G - 1N5408G)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

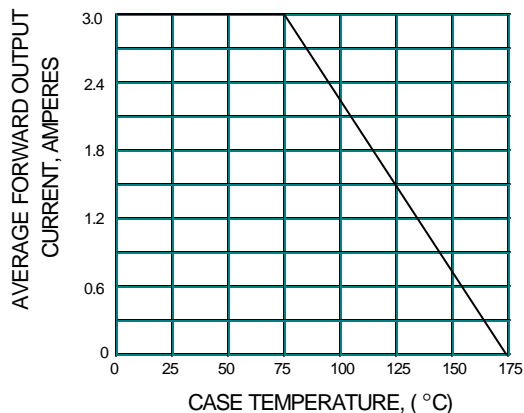


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

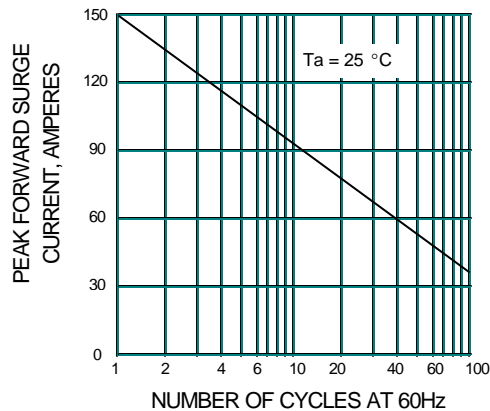


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

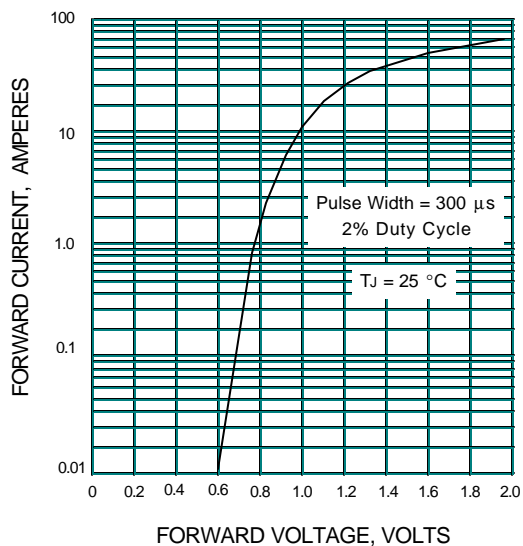


FIG.4 - TYPICAL JUNCTION CAPACITANCE

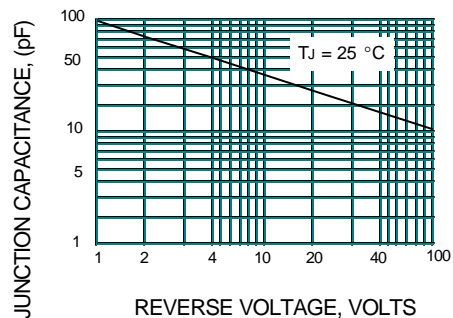


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

